

BAS16/MMBD4148/MMBD914

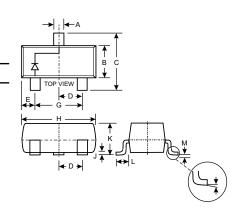
SURFACE MOUNT SWITCHING DIODE

Features

- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- High Conductance

Mechanical Data

- Case: SOT-23, Molded Plastic
- Case material UL Flammability Rating Classification 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Marking: KA6, KA2, K5D (See Page 3)
- Weight: 0.008 grams (approx.)



SOT-23									
Dim	Dim Min Max								
Α	0.37	0.51							
В	1.20	1.40							
С	2.30	2.50							
D	0.89	1.03							
E	0.45	0.60							
G	1.78	2.05							
Н	2.80	3.00							
J	0.013	0.10							
K	0.903	1.10							
L	0.45	0.61							
М	0.85	0.80							
α	0°	8°							
All Din	All Dimensions in mm								

Maximum Ratings @ TA = 25°C unless otherwise specified

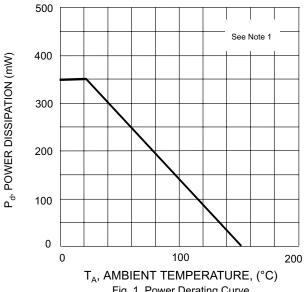
Characteristic	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V _{RM}	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	75	V
RMS Reverse Voltage	V _{R(RMS)}	53	V
Forward Continuous Current (Note 1)	I _{FM}	300	mA
Average Rectified Output Current (Note 1)	lo	200	mA
Non-Repetitive Peak Forward Surge Current @ t = 1.0µs @ t = 1.0s	I _{FSM}	2.0 1.0	A
Power Dissipation (Note 1)	Pd	350	mW
Thermal Resistance Junction to Ambient Air (Note 1)	$R_{ heta JA}$	357	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150	°C

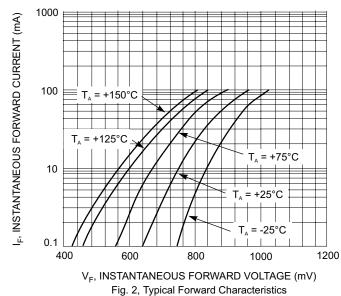
Electrical Characteristics @ TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	$V_{(BR)R}$	75	_	V	I _R = 100μA
Forward Voltage (Note 2)	V _{FM}	_	0.715 0.855 1.0 1.25	V	I _F = 1.0mA I _F = 10mA I _F = 50mA I _F = 150mA
Leakage Current (Note 2)	I _{RM}	_	1.0 50 30 25	μΑ μΑ μΑ nA	$V_R = 75V$ $V_R = 75V$, $T_j = 150$ °C $V_R = 25V$, $T_j = 150$ °C $V_R = 20V$
Total Capacitance	Ст	_	2.0	pF	V _R = 0, f = 1.0MHz
Reverse Recovery Time	t _{rr}	_	4.0	ns	$I_F = I_R = 10 \text{mA},$ $I_{rr} = 0.1 \text{ x } I_R, R_L = 100 \Omega$

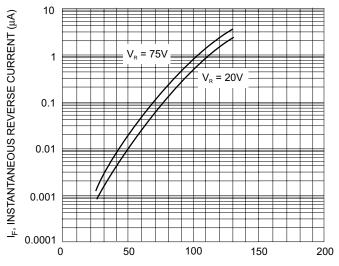
Notes: 1. Device mounted on glass epoxy PCB 1.6" x 1.6" x 0.06"; mounting pad for the cathode lead min. 0.93ia.

2. Short duration test pulse used to minimize self-heating effect.









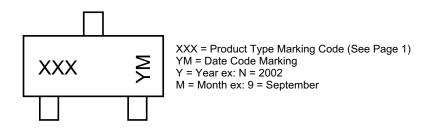
T_j, JUNCTION TEMPERATURE (°C) Fig. 3, Typical Reverse Characteristics

Ordering Information (Note 3)

Device	Packaging	Shipping
BAS16-7 MMBD4148-7 MMBD914-7	SOT-23	3000/Tape & Reel

Notes: 3. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



Date Code Key

Year	1998	1999	1999 2000		2002	2003	2004	
Code	J	K	L	М	N	Р	R	

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D